## NSN 5961-01-581-0616

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-581-0616 **Inclosure Material:** Metal **Overall Length:** Between 38.50 millimeters and 39.30 millimeters **Overall Height:** Between 19.32 millimeters and 22.02 millimeters **Overall Width:** Between 25.00 millimeters and 26.00 millimeters **Overall Diameter:** Between 25.00 millimeters and 26.00 millimeters **Mounting Facility Quantity:** 2 Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Internal Junction Configuration:** Npn **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 reach through voltage **Current Rating Per Characteristic:** 15.00 amperes forward current, average **Power Rating Per Characteristic:** 175.0 watts total power dissipation **Transfer Ratio:** 300.0 static forward current transfer ratio, common-emitter and 2.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No